

# IPB80N06S207ATMA4

### IPB80N06S207ATMA4 Information



For Reference Only

Part Number IPB80N06S207ATMA4
Manufacturer Infineon Technologies

Category Discrete Semiconductor Products
Transistors - FETs, MOSFETs - Single

**Description** MOSFET N-CH 55V 80A TO263-3

**Package** TO-263-3, D2Pak (2 Leads + Tab), TO-263AB

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

# **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









### IPB80N06S207ATMA4 Specifications

| Manufacturer Part Number               | IPB80N06S207ATMA4                         |       |
|--|---|-------|
| Manufacturer                           | Infineon Technologies                     |       |
| Category                               | Discrete Semiconductor Products           |       |
|  | Transistors - FETs, MOSFETs - Single      |       |
| Package                                | TO-263-3, D2Pak (2 Leads + Tab), TO-263AB |       |
| Series                                 | OptiMOS?                                  |       |
| FET Type                               | N-Channel                                 |       |
| Technology                             | MOSFET (Metal Oxide)                      |       |
| Drain to Source Voltage (Vdss)         | 55V                                       |       |
| Current - Continuous Drain (Id) @ 25°C | 80A (Tc)                                  |       |
| Drive Voltage (Max Rds On, Min Rds On) | 10V                                       |       |
| Vgs(th) (Max) @ Id                     | 4V @ 180μA                                |       |
| Gate Charge (Qg) (Max) @ Vgs           | 110nC @ 10V                               |       |
| Input Capacitance (Ciss) (Max) @ Vds   | 3400pF @ 25V                              |       |
| Vgs (Max)                              | ±20V                                      |       |
| FET Feature                            | -   |       |
| Power Dissipation (Max)                | 250W (Tc)                                 |       |
| Rds On (Max) @ Id, Vgs                 | 6.3 mOhm @ 68A, 10V                       |       |
| Operating Temperature                  | -55°C ~ 175°C (TJ)                        |       |
| Mounting Type                          | Surface Mount                             |       |
| Supplier Device Package                | PG-TO263-3-2                              |       |
| Package / Case                         | TO-263-3, D2Pak (2 Leads + Tab), TO-263AB |       |
|  | Report er                                 | rors? |

#### IPB80N06S207ATMA4 Guarantees



#### **Ouality Guarantees**

We provide 90 days warranty. \*

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

### IPB80N06S207ATMA4 Payment Methods



















## IPB80N06S207ATMA4 Shipping Methods













If you have any question about IPB80N06S207ATMA4, please do not hesitate to contact us!

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